International **ICR** Rectifier

HIGH RELIABILITY RADIATION HARDENED DC/DC CONVERTER

Description

The G-Series of DC/DC converters are radiation hardened, high reliability converters designed for extended operation in hostile environments. Their small size and low weight make them ideal for applications such as geostationary earth orbit satellites and deep space probes. They exhibit a high tolerance to total ionizing dose, single event effects and environmental stresses such as temperature extremes, mechanical shock, and vibration. All components are fully derated to meet the requirements of MIL-STD-975, MIL-STD-1547 and GSFC PPL-21 Appendix B. Extensive documentation including Radiation Susceptibility, Thermal, Stress, Worst Case, Failure Modes and Effects analyses and MTBF are available for customer review and included with each order.

The converters incorporate a fixed frequency single ended forward topology with magnetic feedback and an internal EMI filter that utilizes metallized filmcapacitors instead of large multilayer ceramic capacitors for improved reliability. These converters are capable of meeting the conducted emissions and conducted susceptibility requirements of MIL-STD-461C without any additional components. External inhibit and synchronization input and output allow these converters to be easily incorporated into larger power systems. They are enclosed in a hermetic 3" x 2" x 0.4" package constructed of an Aluminum/Silicon-Carbide (Al/SiC) base and an Alloy 48 ring frame and they weigh less than 90 grams. The package utilizes rugged ceramic feed-through copper core pins and is sealed using parallel seam welding.

Full environmental screening includes temperature cycling, constant acceleration, fine and gross leak, particle impact noise detection (PIND), radiographic and 320 hours burn-in.

Non-flight versions of the G-Series converters are available for system development purposes. Variations in electrical specifications and screening to meet custom requirements can be accommodated.

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PD-95890

M3G2803R312T

28V Input, Triple Output



Features

- Total Dose > 200 Krad(Si), typically usable to > 1 Mrad(Si)
- SEE 82 MeV.cm²/mg
- Internal EMI Filter, converter capable of meeting MIL-STD-461C CEO3 and CS01
- Low Weight, < 90 grams
- Magnetically Coupled Feedback
- 18V to 50V DC Input Range
- Up to 33W Output Power
- Main Output Isolated from Dual Outputs
- High Efficiency to 80%
- -55°C to +125°C Operating Temperature Range
- 100MΩ @ 500VDC Isolation
- Under-Voltage Lockout
- Synchronization Input and Output
- Short Circuit and Overload Protection
- Output Over Voltage Limiter
- External Inhibit
- > 5,000,000 Hour MTBF

Applications

- Geostationary Earth Orbit Satellites (GEO)
- Deep Space Satellites / Probes
- Strategic Weapons and Communication Systems

Circuit Description

The G-Series converters utilize a single-ended forward topology with resonant reset. The nominal switching frequency is 500kHz. Electrical isolation and tight output regulation are achieved through the use of a magnetically coupled feedback. Voltage feed-forward with duty factor limiting provides high line rejection and protection against output over voltage in the event of an internal control loop failure. This mechanism limits the maximum output voltage to approximately 20% over the nominal regardless of the line voltage.

An internal EMI filter reduces the conducted emissions to less than 5mA rms on the input power leads. A two-stage output filter reduces the typical output ripple to less than 20mV peak-to-peak.

The main (+5 volt) output is regulated by the control loop and typically exhibits better than 1% regulation. The auxiliary (± 12 volt or ± 15 volt) outputs are maintained through tight coupling in the power transformer and main output filter inductor and typically exhibit better than 5% regulation. The main output and auxiliary outputs are isolated from each other.

Output power is limited under any load fault condition to approximately 125% of rated. An overload condition causes the converter output to behave like a constant current source with the output voltage dropping below nominal. The converter will resume normal operation when the load current is reduced below the current limit point. This protects the converter from both overload and short circuit conditions. The current limit point exhibits a slightly negative temperature coefficient to reduce the possibility of thermal runaway.

An under-voltage lockout circuit prohibits the converter from operating when the line voltage is too low to maintain the output voltage. The converter will not start until the line voltage rises to approximately 16.5 volts and will shut down when the input voltage drops 15.5 volts. The one volt of hysteresis reduces

the possibility of line noise interfering with the converter's start-up and shut down.

An external inhibit port is provided to control converter operation. The nominal threshold relative to the input return (pin 2) is 1.4V. If 2.0 volts or greater are applied to the Inhibit pin (pin 3) then the converter will operate normally. A voltage of 0.8V or less will cause the converter to shut-down. The pin may be left open for normal operation and has a nominal open circuit voltage of 4.0V.

Synchronization input and output allow multiple converters to operate at a common switching frequency. Converters can be synchronized to one another or to an externally provided clock. This can be used to eliminate beat frequency noise or to avoid creating noise at certain frequencies for sensitive systems.

Design Methodology

The G-Series was developed using a proven conservative design methodology which includes selecting radiation tolerant and established reliability components and fully derating to the requirements of MIL-STD-975 and MIL-STD-1547. Careful sizing of decoupling capacitors and current limiting resistors minimizes the possibility of photo-current burn-out. Heavy derating of the radiation hardened power MOSFET virtually eliminates the possibility of SEGR and SEB. A magnetic feedback circuit is utilized instead of opto-couplers to minimize temperature, radiation and aging sensitivity. PSPICE and RadSPICE were used extensively to predict and optimize circuit performance for both beginning and end-of-life. Thorough design analyses include Radiation Susceptibility (TREE), Worst Case, Stress, Thermal, Failure Modes and Effects (FMEA) and Reliability (MTBF).

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Absolute Maximum Ratings

Input voltage range -Operating temperature - -55°C to +135°C Storage temperature - -55°C to +135°C

-0.5Vdc to +80Vdc Output power - Internally limited Lead temperature - +300°C for 10 seconds

Recommended Operating Conditions

Input voltage range -	18Vdc to +60Vdc
Input voltage range ¹ -	18Vdc to +50Vdc
Output power -	0 to Max. Rated
Operating temperature ² -	-55°C to +125°C
Operating temperature ¹ -	-55°C to +70°C

¹Meets derating per MIL-STD-975 ²For operation at +125°C see table note 14

		Conditions -55°C ≤ T _C ≤ +85°C		Limits			
	Group A	$V_{IN} = 28V DC \pm 5\%, C_I = 0$					
Parameter	Subgroup	unless otherwiese specified		Nom.	Max.	Unit	
Input Voltage	1,2,3	Note 2	18	28	50	V	
		I _{OUT} = 100% Rated Load, Note 5					
	1	(main	3.28	3.3	3.32		
		(aux.	±11.60	±12.00	±12.40		
						V	
	2,3	(main	3.24		3.36		
		(aux.	±11.40		±12.60		
Output Power (P _{OUT})	1,2,3	V _{IN} = 18, 28, 50 Volts, Note 2	0		33.2	W	
		V _{IN} = 18, 28, 50 Volts, Notes 2,3,4,5					
Output Current (I _{OUT})	1,2,3	(main	400		4000	mΔ	
		(aux.	83		±833		
		V _{IN} = 18, 28, 50 Volts					
Line Regulation (VR _{LINE})	1,2,3	I _{OUT} = 10, 50, 100% Rated Load, Note 5					
		(main	-10		10	mV	
		(aux.	-120		120		
		V _{IN} = 18, 28, 50 Volts					
Load Regulation (VR _{LOAD})	1,2,3	I _{OUT} = 10, 50, 100% Rated Load, Notes 5,13					
		(main	-30		30	mV	
		(aux.	-400		400		
	100	$V_{IN} = 18, 28, 50$ VOIts	0.5		0.5	0/	
Cross Regulation (VR _{CROSS})	1,2,3	1007 = 2.04 to 1.04 and 2.0 to 4.04	-3.5		3.5	70	
		$I_{OUT} = 0$, Pin 3 open			80		
Input Current (I _{IN})	1,2,3	Pin 3 shorted to Pin 2			5.0	mA	
		V _{IN} = 18, 28, 50 Volts					
Output Ripple (V _{BIP})	1,2,3	I _{OUT} = 10, 50, 100% Rated Load, Notes 5, 6					
		(main		20	30		
		(aux.		30	60	mv _{P-P}	

Electrical Performance Characteristics

For Notes to Specifications, refer to page 5

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Electrical Performance Characteristics (continued)

		Conditions -55°C ≤ T _C ≤ +85°C	Limits			
Paramatar	Group A	$V_{\rm IN} = 28V \rm DC \pm 5\%, C_L = 0$	Min	Nom	Mox	Linit
	Subgroup	Syna Input (Pin 4) open	17111.	500	IVIAX.	
Switching Frequency (F _S)	1,2,3	Sync. Input (Pin 4) open	450	500	550	
Elliciency (EFF)	1,2,3	$I_{OUT} = 100 \%$ Raied Load , Note 5	72	75		70
						V
Drive Overset (Disk)			3.0		5.0	v
Drive Current (Sink)	1,2,3	Note 1			100	μΑ
Voltage Range			-0.5		50	V
Synchronization Input						
Frequency Range			450		600	KHZ
Pulse High Level			4.0		10	V
Pulse Low Level	1,2,3	Ext. Clock on Sync. Input (Pin 4), Note 1	-0.5		0.5	V
Pulse Transition Time			40			V/μS
Pulse Duty Cycle			20		80	%
Current Limit Point						
Expressed as a Percentage	1,2,3	V _{OUT} = 90% of Nominal, Note 5			135	%
of Full Rated Output Power						
Power Dissipation, Load Fault (P_D)	1,2,3	Short Circuit, Overload, Note 8			20	W
Output Response to						
Step Load Changes (V _{TLD})	4,5,6	Half Load to/from Full Load, Notes 5, 9	-300		300	mV pk
Recovery Time,						
Step Load Changes (T _{TLD})	4,5,6	Half Load to/from Full Load, Notes 5, 9, 10			100	μS
Output Response to		18V to/from 50V				
Step Line Changes (V _{TLN})	4,5,6	I _{OUT} = 100% Rated Load, Notes 1, 5, 10, 11	-300		300	mV pk
Recovery Time,		18V to/from 50V				
Step Line Changes (T _{TLN})	4,5,6	I _{OUT} = 100% Rated Load, Notes 1, 5, 10, 11			100	μS
Turn-on Response		No Load, Full Load, Notes 5, 12				
Overshoot (V _{OS})		(main)			500	
	4,5,6	(aux.)			750	mv
Turn-on Delay(T _{DLY})			1.0		5.0	mS
Capacitive Load (C _L)		I _{OUT} = 100% Rated Load,				
	1,2,3	No effect on DC Performance. Notes 1.5.7				
		(main)			1000	
		(Each aux.Output)			200	μr
Line Rejection	1	I _{OUT} = 100% Rated Load,	40	60		dB
-		DC to 50KHz, Notes 1, 5				
Isolation	1	except Pin 10, test @ 500VDC	100			MΩ
Device Weight					90	a
MTBF		MIL-HDBK-217F2, SF, 35°C	5 X 10 ⁶			Hours

For Notes to Specifications, refer to page 5

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Electrical Performance Characteristics (continued)

Table I. Electrical Performance Characteristics - notes

- 1. Parameter is tested as part of design characterization or after design changes. Thereafter, parameter shall be guaranteed to the limits specified.
- 2. Parameter verified during line and load regulation tests.
- 3. Although operation with no load is permissible, light loading on the main output may cause the output voltage of the auxiliary outputs to drop out of regulation. It is therefore recommended that at least 200 mA or 20 percent of the total output power, whichever is greater, be taken from the main output.
- 4. Although operation with no load is permissible, heavy loading on the main output may cause the output voltage of the auxiliary outputs to rise out of regulation. It is therefore recommended that at least 50 mA or 20 percent of the total output power, whichever is greater, be taken from the auxiliary (±12 volts or ±15 volt) outputs.
- 5. Unless otherwise specified, "Rated" load is 13.2W on the main output and 10 watts each on the auxiliary outputs.
- 6. Guaranteed for a D.C. to 20MHz bandwidth. Tested using a 20KHz to 10MHz bandwidth.
- Capacitive load may be any value from 0 to the maximum limit without compromising dc performance. A
 capacitive load in excess of the maximum limit may interfere with the proper operation of the converter's
 overload protection, causing erratic behavior during turn-on.
- 8. Overload power dissipation is defined as the device power dissipation with the load set such that $V_{out} = 90\%$ of nominal.
- 9. Load step transition time \leq 10 μ Sec.
- Recovery time is measured from the initiation of the transient to where V_{OUT} has returned to within ±1% of its steady state value.
- 11. Line step transition time \leq 100 µSec.
- 12. Turn-on delay time from either a step application of input power or a logic low to a logic high transition on the inhibit pin (pin 3) to the point where $V_{out} = 90\%$ of nominal.
- 13. Load is varied for output under test while the remaining outputs are loaded at 50% of rated. Regulation relative to output voltage at 50% rated load.
- 14. For operation at temperatures between +85°C and +125°C, derate the maximum input voltage linearly from 60V to 40V and the maximum output power linearly from 100% to 75%.

International **101** Rectifier

Radiation Performance Characteristics

				Highest	
				Level	
Test Inspection	Method	Min	Тур	Tested	Unit
	MIL-PRF-883, Method 1019				
Total Ionizing Dose (Gamma)	Operating bias applied during exposure,				
	Full Rated Load, V _{IN} = 28V	200	1000	2000	Krads(Si)
Dose Rate (Gamma Dot)	MIL-STD-883, Method 1023				
Temporary Saturation	Operating bias applied during exposure,	1E8		7E10	Rads(Si)
Survival	Full Rated Load, V _{IN} = 28V	4E10	1E11		/sec
Neutron Fluence	MIL-STD-883, Method 1017	8E12	1E13	5.4E13	Neutrons
					/cm ²
	Heavy Ions (LET)				
Single Event Effects	Operating bias applied during exposure,				MeV•cm ²
SEU, SEL, SEGR, SEB	Full Rated Load, V _{IN} = 28V	>82		82	/mg

Device Screening

Test Inspection	Method	Condition	
Element Evaluation	MIL-PRF-38534, class K equivalent		
Nondestructive Bond Pull	MIL-STD-883, Method 2023		
Internal Visual	MIL-STD-883, Method 2017		
Temperature Cycling	MIL-STD-883, Method 1010	С	
Constant Acceleration	MIL-STD-883, Method 2001	A, Y1 axis only	
PIND	MIL-STD-883, Method 2020	А	
Electrical	In accordance with device specification		
Burn-in	MIL-STD-883, Method 1015	320 Hours	
Final Electrical (Group A)	In accordance with device specification		
Seal	MIL-STD-883, Method 1014		
Fine Leak		A1	
Gross Leak		С	
Radiographic	MIL-STD-883, Method 2012		
External Visual	MIL-STD-883, Method 2009		

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Block Diagram - Triple Output

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Conducted Emissions, Positive Lead







Conducted Emissions, Common Mode

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Pin Designation (Triple Output)

Pin No.	Designation	Pin No.	Designation
1	+V Input	8	NC
2	Input Return	9	NC
3	Inhibit	10	Case Ground
4	Sync. Input	11	- Aux. Output
5	Sync. Output	12	Aux. Output Return
6	Main Return	13	+ Aux. Output
7	+ Main Output		

Part Number



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